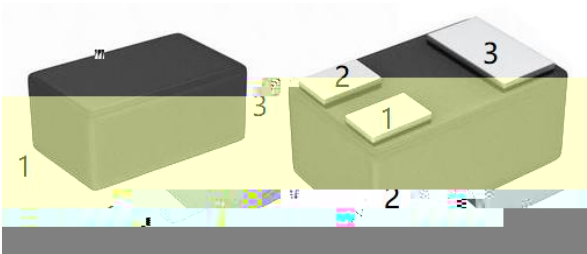


BRCS7002K2ZK
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I	E	E	L	L
DFN1006-3L	N	MOS		
N-Channel Enhancement Mode Field Effect Transistor in a DFN1006-3L Plastic Package.				

2KV
Sensitive gate trigger current and Low Holding current.ESD protected up to 2KV.HF Product.

Intended for use in general purpose switching and phase control applications.



Pin1:G Pin2:S Pin3:D

See Marking Instructions.

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DATA SHEET

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DATA SHEET

/ Electrical Characteristic Curve

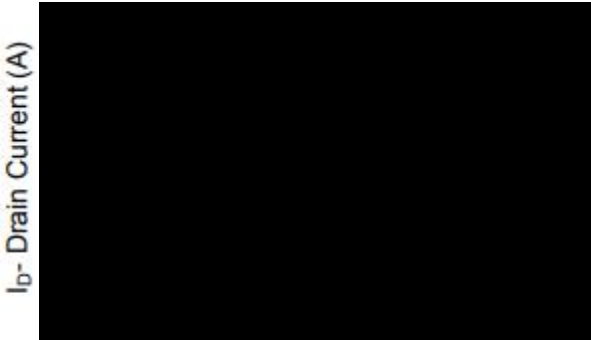
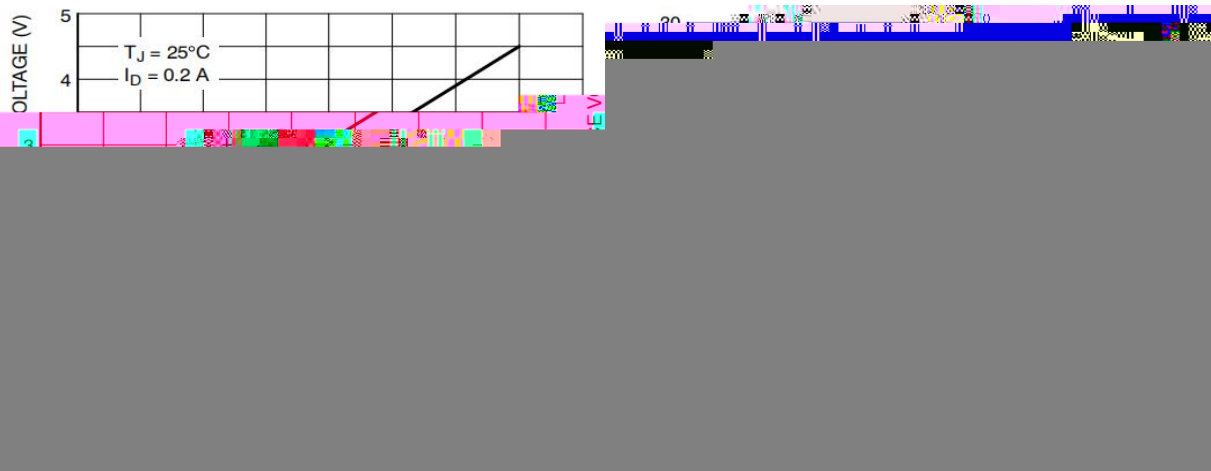
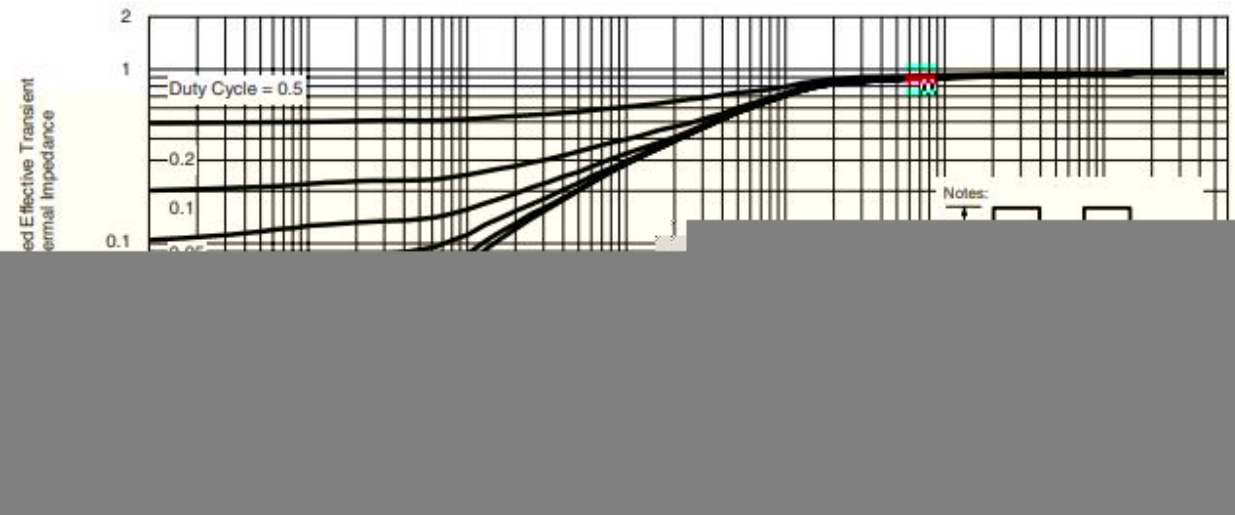
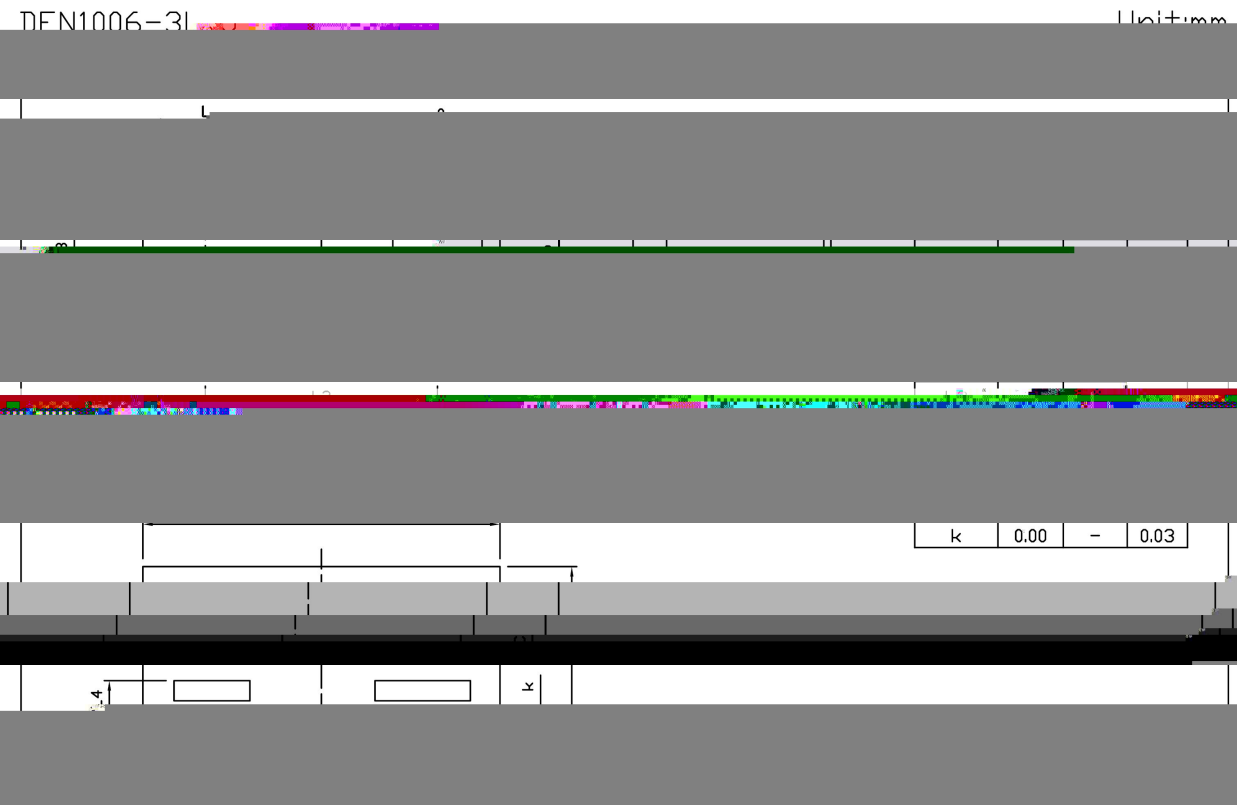


Figure 9 : Safe Operation Area





/ Package Dimensions



/ Marking Instructions



702K2

Note:

702K2: Product Type

